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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Kulbinder K. Banger et al.

Serial No.: 10/698,118 Filing Date: October 31, 2003

Title: SINGLE-SOURCE PRECURSORS FOR TERNARY CHALCOPYRITE MATERIALS, AND METHODS OF MAKING AND USING THE SAME

Docket No.: 35089US1

INFORMATION DISCLOSURE STATEMENT

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Sir:

In accordance with Rule 56, applicants are aware of the publications listed in the enclosed copy of Patent Office Form 1449. Since the Office has waived the requirement under 37 C.F.R §1.98(a)(2)(i) for submitting copies of cited U.S. patents and U.S. patent application publications, a copy of each listed U.S. patent or U.S. patent application publication is not being submitted herewith. Copies of all other cited documents are enclosed. Please charge any fee deficiencies and credit any overpayments to Deposit Account No. 16-0820, Order No. 35089US1.

Respectfully submitted,
PEARNE & GORDON LLP

By: _____
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**I hereby certify that the attached correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on the date indicated below.**

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September 2, 2004
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| INFORMATION DISCLOSURE CITATION BY APPLICANT *(USE SEVERAL SHEETS IF NECESSARY)* Page 1of 1 | | APPLICANT: **Kulbinder K. Banger et al.** | |
| | | FILING DATE: **October 31, 2003** | GROUP ART UNIT: 1621 |



## U.S. PATENT DOCUMENTS

| Examiner Initial | | Document No. | Date | Name | Class | Subclass | Filing Date If Appropriate |
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| | A | | | | | | |
| | B | | | | | | |
| | C | | | | | | |

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*Examiner: Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.